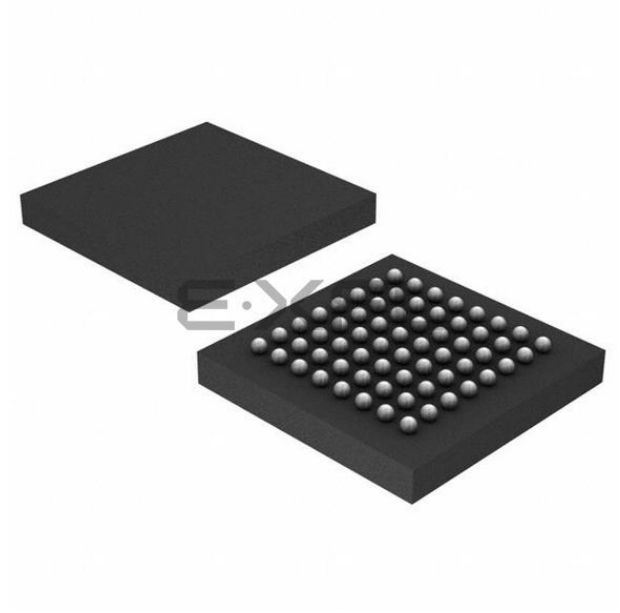

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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	ARM7®
Core Size	32-Bit Single-Core
Speed	60MHz
Connectivity	I²C, SPI, SSI, SSP, UART/USART, USB
Peripherals	DMA, PWM, WDT
Number of I/O	38
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 11x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LFBGA
Supplier Device Package	-
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/str751fr1h6

1 Description

The STR750 family of 32-bit microcontrollers combines the industry-standard ARM7TDMI® 32-bit RISC core, featuring high performance, very low power, and very dense code, with a comprehensive set of peripherals and ST's latest 0.18µ embedded Flash technology. The STR750 family comprises a range of devices integrating a common set of peripherals as well as USB, CAN and some key innovations like clock failure detection and an advanced motor control timer. It supports both 3.3V and 5V, and it is also available in an extended temperature range (-40 to +105°C). This makes it a genuine general purpose microcontroller family, suitable for a wide range of applications:

- Appliances, brushless motor drives
- USB peripherals, UPS, alarm systems
- Programmable logic controllers, circuit breakers, inverters
- Medical and portable equipment

2 Device overview

Table 2. Device overview

Features	STR755FR0 STR755FR1 STR755FR2	STR751FR0/ STR751FR1/ STR751FR2	STR752FR0/ STR752FR1/ STR752FR2	STR755FV0 STR755FV1/ STR755FV2	STR750FV0/ STR750FV1/ STR750FV2
Flash - Bank 0 (bytes)	64K/128K/256K				
Flash - Bank 1 (bytes)	16K RWW				
RAM (bytes)	16K				
Operating Temperature.	Ambient temp.:-40 to +85°C / -40 to +105°C (see *Table 49*) Junction temp. -40 to + 125 °C (see *Table 10*)				
Common Peripherals	3 UARTs, 2 SSPs, 1 I2C, 3 timers 1 PWM timer, 38 I/Os 13 Wake-up lines, 11 A/D Channels			3 UARTs, 2 SSPs, 1 I^2C, 3 timers 1 PWM timer, 72 I/Os 15 Wake-up lines, 16 A/D Channels	
USB/CAN peripherals	None	USB	CAN	None	USB+CAN
Operating Voltage	3.3V or 5V	3.3V	3.3V or 5V		
Packages (**x**)	**T**=LQFP64 10x10, **H**=LFBGA64			**T**=LQFP100 14x14, **H**=LFBGA100	

periodic interrupt. It is clocked by an external 32.768 kHz oscillator or the internal low power RC oscillator. The RC has a typical frequency of 300 kHz and can be calibrated.

WDG (watchdog timer)

The watchdog timer is based on a 16-bit downcounter and 8-bit prescaler. It can be used as watchdog to reset the device when a problem occurs, or as free running timer for application time out management.

Timebase timer (TB)

The timebase timer is based on a 16-bit auto-reload counter and not connected to the I/O pins. It can be used for software triggering, or to implement the scheduler of a real-time operating system.

Synchronizable standard timers (TIM2:0)

The three standard timers are based on a 16-bit auto-reload counter and feature up to 2 input captures and 2 output compares (for external triggering or time base / time out management). They can work together with the PWM timer via the Timer Link feature for synchronization or event chaining. In reset state, timer Alternate Function I/Os are connected to the same
I/O ports in both 64-pin and 100-pin devices. To optimize timer functions in 64-pin devices, timer Alternate Function I/Os can be connected, or “remapped”, to other I/O ports as summarized in *Table 3* and detailed in *Table 6*. This remapping is done by the application via a control register.

Table 3. Standard timer alternate function I/Os

Standard timer functions		Number of alternate function I/Os		
		100-pin package	64-pin package	
			Default mapping	Remapped
TIM 0	Input Capture	2	1	2
	Output Compare/PWM	2	1	2
TIM 1	Input Capture	2	1	1
	Output Compare/PWM	2	1	1
TIM 2	Input Capture	2	2	2
	Output Compare/PWM	2	1	2

Any of the standard timers can be used to generate PWM outputs. One timer (TIM0) is mapped to a DMA channel.

Motor control PWM timer (PWM)

The Motor Control PWM Timer (PWM) can be seen as a three-phase PWM multiplexed on 6 channels. The 16-bit PWM generator has full modulation capability (0...100%), edge or centre-aligned patterns and supports dead-time insertion. It has many features in common with the standard TIM timers which has the same architecture and it can work together with the TIM timers via the Timer Link feature for synchronization or event chaining.The PWM timer is mapped to a DMA channel.

4 Pin description

Figure 2. LQFP100 pinout

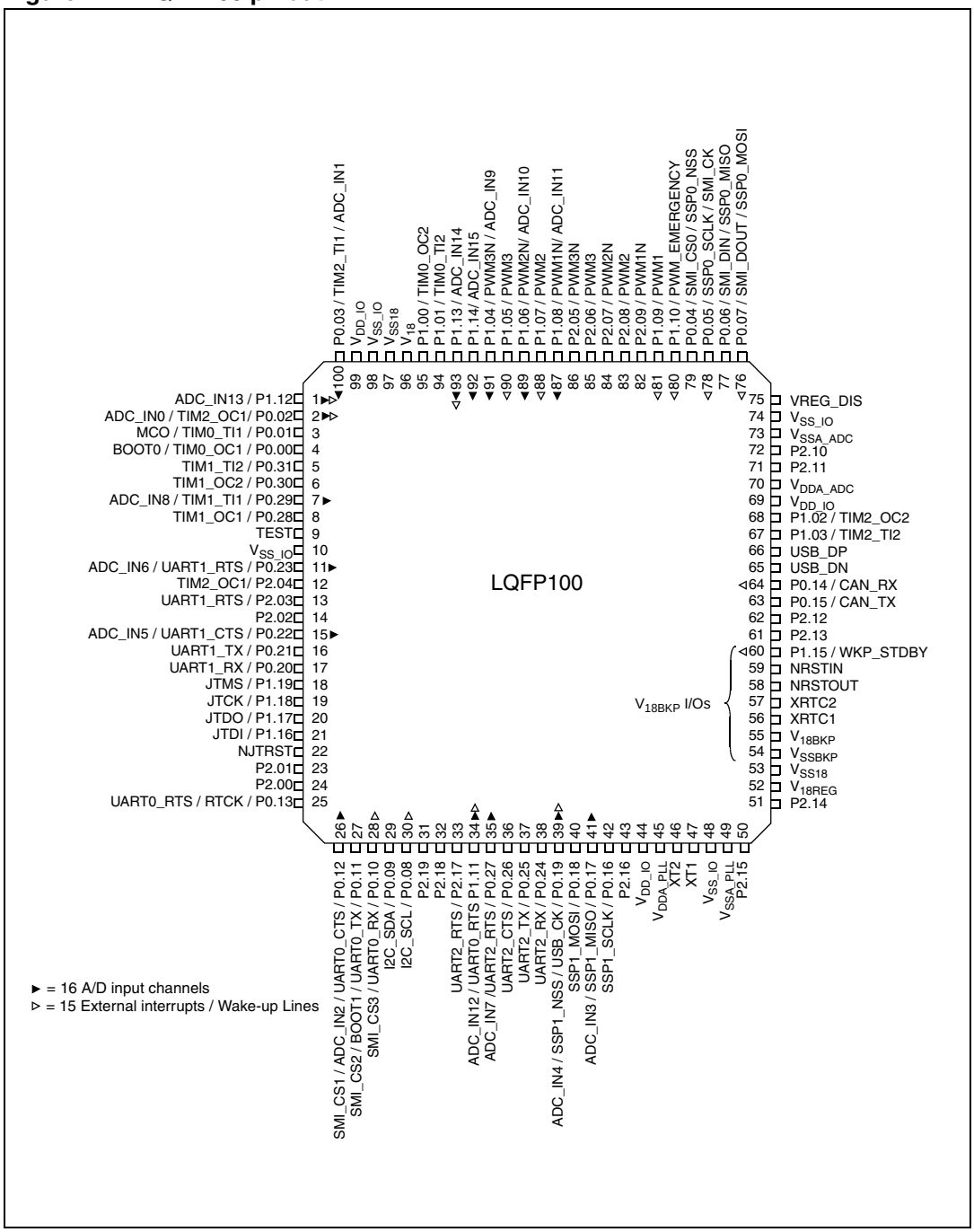


Table 6. STR750F pin description (continued)

Pin n°				Pin name	Type	Input				Output			Usable in Standby	Main function (after reset)	Alternate function	
LQFP100(1)	LFBGA100(1)	LQFP64(2)	LFBGA64(2)			Input Level	floating	pu/pd	Ext. int /Wake-up	Capability	OD (3)	PP				
68	A10			P1.02 / TIM2_OC2	I/O	T_T	X	X		O2	X	X		**Port 1.02**	TIM2: Output compare 2 (remappable to P0.06)(8)	
69	D7	44	C6	VDD_IO	S									Supply Voltage for digital I/Os		
70	D8	45	D6	VDDA_ADC	S									Supply Voltage for A/D converter		
71	C9			P2.11	I/O	T_T	X	X		O2	X	X		**Port 2.11**		
72	B10			P2.10	I/O	T_T	X	X		O2	X	X		**Port 2.10**		
73	C8	46	D7	VSSA_ADC	S									Ground Voltage for A/D converter		
74	C7	47	C7	VSS_IO	S									Ground Voltage for digital I/Os		
75	E8	48	D5	VREG_DIS	I	T_T								Voltage Regulator Disable input		
76	A9	49	A8	P0.07 / SMI_DOUT / SSP0_MOSI	I/O	T_T	X	X	EIT2	O4	X	X		**Port 0.07**	Serial Memory Interface: data output	SSP0: Master out Slave in data
77	A8	50	A7	P0.06 / SMI_DIN / SSP0_MISO	I/O	T_T	X	X		O4	X	X		**Port 0.06**	Serial Memory Interface: data input	SSP0: Master in Slave out data
78	A7	51	A6	P0.05 / SSP0_SCLK / SMI_CK	I/O	T_T	X	X	EIT1	O4	X	X		**Port 0.05**	SSP0: Serial clock	Serial Memory Interface: Serial clock output
79	B7	52	B6	P0.04 / SMI_CS0 / SSP0_NSS	I/O	T_T	X	X		O4	X	X		**Port 0.04**	Serial Memory Interface: chip select output 0	SSP0: Slave select input
80	C5	53	B7	P1.10 PWM_EMERGENCY	I/O	T_T	X	X	EIT10	O2	X	X		**Port 1.10**	PWM: Emergency input	
81	B6	54	B5	P1.09 / PWM1	I/O	T_T	X	X	EIT9	O4	X	X		**Port 1.09**	PWM: PWM1 output	
82	C6			P2.09 / PWM1N	I/O	T_T	X	X		O2	X	X		**Port 2.09**	PWM: PWM1 complementary output(4)	
83	G7			P2.08 / PWM2	I/O	T_T	X	X		O2	X	X		**Port 2.08**	PWM: PWM2 output(4)	
84	G6			P2.07 / PWM2N	I/O	T_T	X	X		O2	X	X		**Port 2.07**	PWM: PWM2 complementary output(4)	
85	F7			P2.06 / PWM3	I/O	T_T	X	X		O2	X	X		**Port 2.06**	PWM: PWM3 output(4)	
86	F6			P2.05 / PWM3N	I/O	T_T	X	X		O2	X	X		**Port 2.05**	PWM: PWM3 complementary output(4)	
87	A6	55	A5	P1.08 / PWM1N / ADC_IN11	I/O	T_T	X	X		O4	X	X		**Port 1.08**	PWM: PWM1 complementary output(8)	ADC: analog input 11
88	B5	56	B4	P1.07 / PWM2	I/O	T_T	X	X	EIT8	O4	X	X		**Port 1.07**	PWM: PWM2 output(4)	
89	A5	57	A4	P1.06 / PWM2N / ADC_IN10	I/O	T_T	X	X		O4	X	X		**Port 1.06**	PWM: PWM2 complementary output(4)	ADC: analog input 10
90	B4	58	B3	P1.05 / PWM3	I/O	T_T	X	X	EIT7	O4	X	X		**Port 1.05**	PWM: PWM3 output(4)	

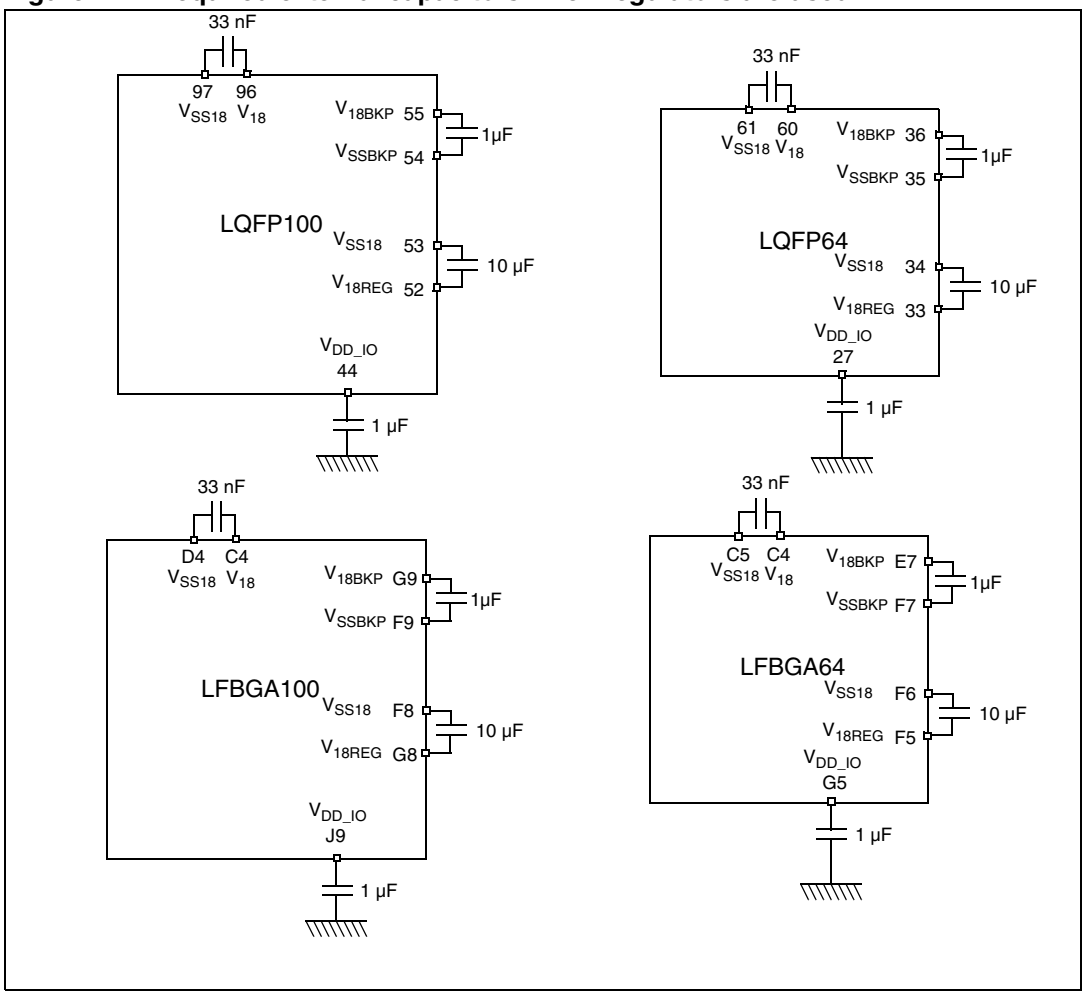
Table 6. STR750F pin description (continued)

Pin n°				Pin name	Type	Input				Output			Usable in Standby	Main function (after reset)	Alternate function	
LQFP100(1)	LFBGA100(1)	LQFP64(2)	LFBGA64(2)			Input Level	floating	pu/pd	Ext. int /Wake-up	Capability	OD (3)	PP				
91	A4	59	A3	P1.04 / PWM3N / ADC_IN9	I/O	T_T	**X**	X		O4	X	X		**Port 1.04**	PWM: PWM3 complementary output(4)	ADC: analog input 9
92	A3			P1.14 / ADC_IN15	I/O	T_T	**X**	X		O8	X	X		**Port 1.14**	ADC: analog input 15	
93	A2			P1.13 / ADC_IN14	I/O	T_T	**X**	X	EIT13	O8	X	X		**Port 1.13**	ADC: analog input 14	
94	D5			P1.01 / TIM0_TI2	I/O	T_T	**X**	X		O2	X	X		**Port 1.01**	TIM0: Input Capture / trigger / external clock 2 (remappable to P0.05)(8)	
95	E6			P1.00 / TIM0_OC2	I/O	T_T	**X**	X		O2	X	X		**Port 1.00**	TIM0: Output compare 2 (remappable to P0.04)(8)	
96	C4	60	C4	V18	S									Stabilization for main voltage regulator. Requires external capacitors 33nF between V18 and VSS18. See *Figure 4.2*. To be connected to the 1.8V external power supply when embedded regulators are not used.		
97	D4	61	C5	VSS18	S									Ground Voltage for the main voltage regulator.		
98	D3	62	A2	VSS_IO	S									Ground Voltage for digital I/Os		
99	C3	63	B2	VDD_IO	S									Supply Voltage for digital I/Os		
100	A1	64	A1	P0.03 / TIM2_TI1 / ADC_IN1	I/O	T_T	**X**	X		O2	X	X		**Port 0.03**	TIM2: Input Capture / trigger / external clock 1	ADC: analog input 1

1. For STR755FVx part numbers, the USB pins must be left unconnected.
2. The non available pins on LQPFP64 and LFBGA64 packages are internally tied to low level.
3. None of the I/Os are True Open Drain: when configured as Open Drain, there is always a protection diode between the I/O pin and VDD_IO.
4. In the 100-pin package, this Alternate Function is duplicated on two ports. You can configure one port to use this AF, the other port is then free for general purpose I/O (GPIO), external interrupt/wake-up lines, or analog input (ADC_IN) where these functions are listed in the table.
5. It is mandatory that the NJTRST pin is reset to ground during the power-up phase. It is recommended to connect this pin to NRSTOUT pin (if available) or NRSTIN.
6. After reset, these pins are enabled as JTAG alternate function see (*Port reset state on page 16*). To use these ports as general purpose I/O (GPIO), the DBGOFF control bit in the GPIO_REMAP0R register must be set by software (in this case, debugging these I/Os via JTAG is not possible).
7. There are two different TQFP and BGA 64-pin packages: in the first one, pins 41 and 42 are mapped to USB DN/DP while for the second one, they are mapped to P0.15/CAN_TX and P0.14/CAN_RX.
8. For details on remapping these alternate functions, refer to the GPIO_REMAP0R register description.

4.2 External components

Figure 4. Required external capacitors when regulators are used



Power supply scheme 2: Dual external 1.8V and 3.3V supply

Figure 9. Power supply scheme 2

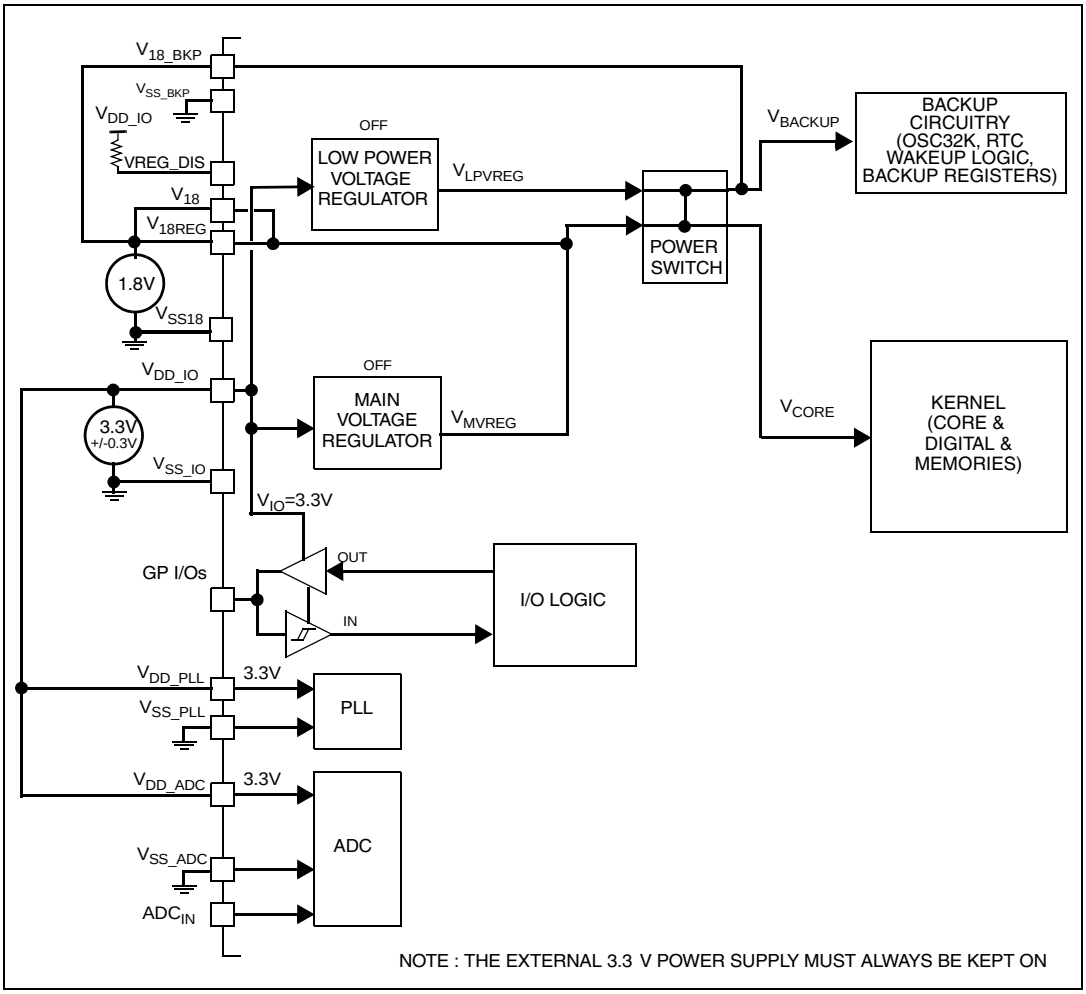


Figure 14. Power consumption measurements in power scheme 3 (regulators enabled)

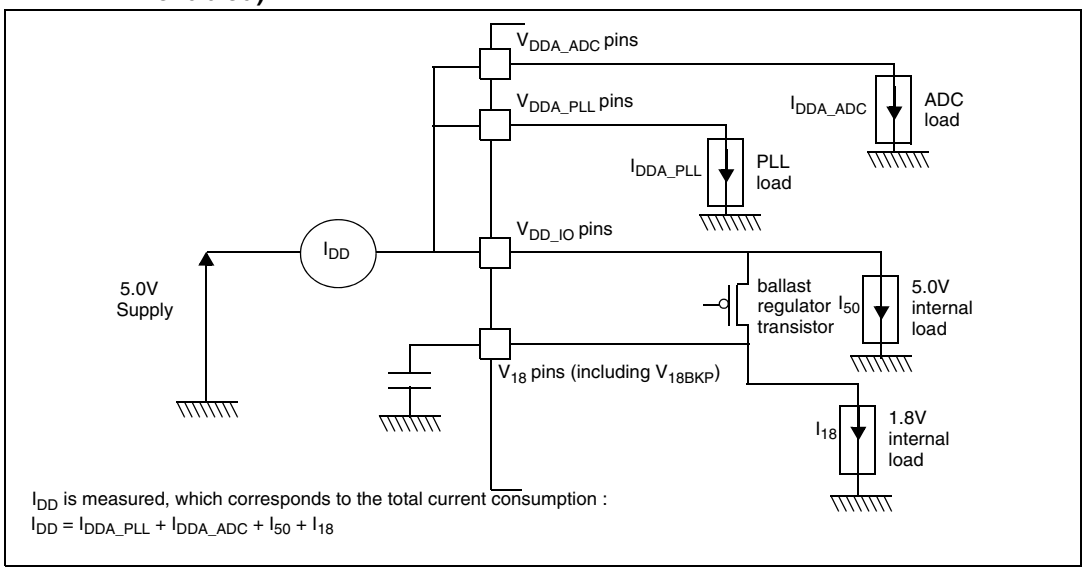
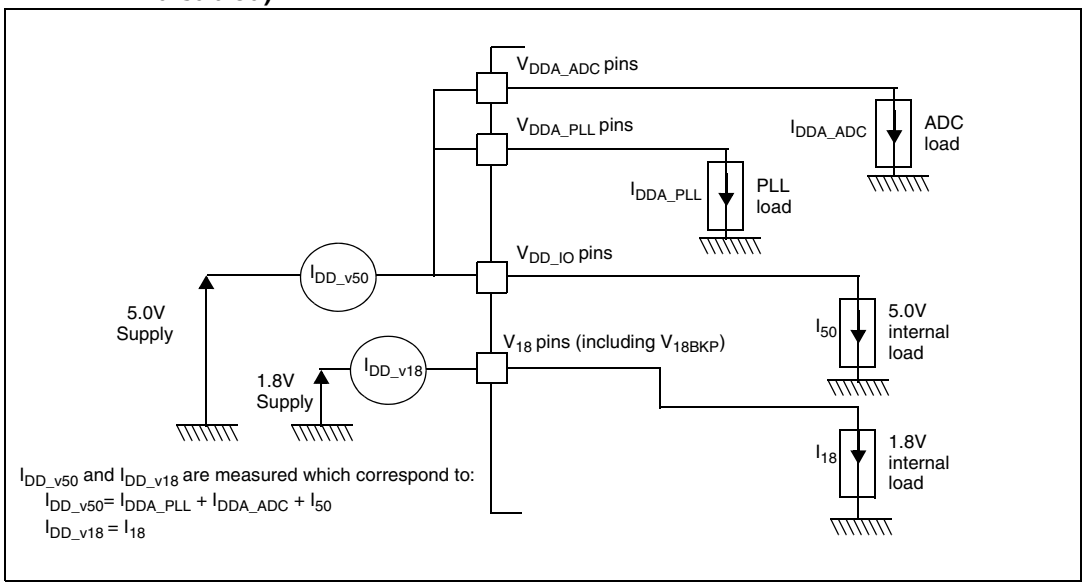


Figure 15. Power consumption measurements in power scheme 4 (regulators disabled)



6.3.4 Supply current characteristics

The current consumption is measured as described in *Figure 12 on page 30* and *Figure 13 on page 30*.

Subject to general operating conditions for V_{DD_IO}, and T_A

Maximum power consumption

For the measurements in *Table 13* and *Table 14*, the MCU is placed under the following conditions:

- All I/O pins are configured in output push-pull 0
- All peripherals are disabled except if explicitly mentioned.
- Embedded Regulators are used to provide 1.8 V (except if explicitly mentioned).

Table 13. Maximum power consumption in RUN and WFI modes

Symbol	Parameter	Conditions (1)		Typ (2)	Max (3)	Unit
I_{DD}	Supply current in RUN mode	External Clock with PLL multiplication, code running from RAM, all peripherals enabled in the MRCC_PLCKEN register: f_{HCLK}=60 MHz, f_{PCLK}=30 MHz Single supply scheme see *Figure 12* / *Figure 14*	3.3V and 5V range	80	90	mA
	Supply current in WFI mode	External Clock, code running from RAM: f_{HCLK}=60 MHz, f_{PCLK}=30 MHz Single supply scheme see *Figure 12*./ *Figure 14* Parameter setting BURST=1, WFI_FLASHEN=1	3.3V and 5V range	62	67	mA

1. The conditions for these consumption measurements are described at the beginning of *Section 6.3.4*.
2. Typical data are based on T_A=25°C, V_{DD_IO}=3.3V or 5.0V and V_{18}=1.8V unless otherwise specified.
3. Data based on product characterisation, tested in production at V_{DD_IO} max and V_{18} max (1.95V in dual supply mode or regulator output value in single supply mode) and T_A max.

Figure 16. Power consumption in STOP mode in Single supply scheme (3.3 V range)

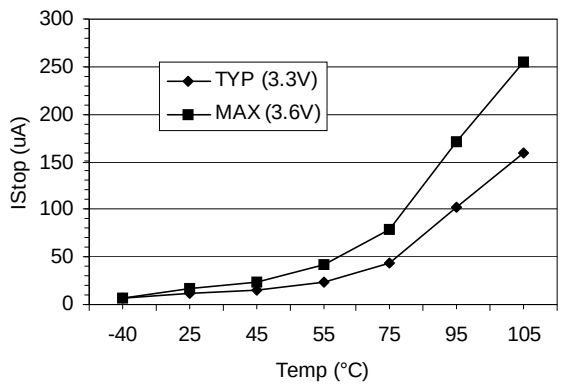


Figure 17. Power consumption in STOP mode Single supply scheme (5 V range)

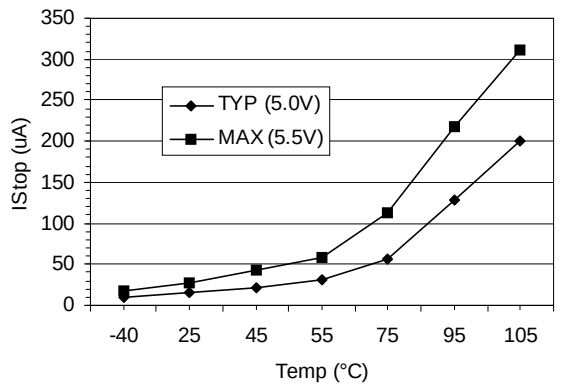


Figure 18. Power consumption in STANDBY mode (3.3 V range)

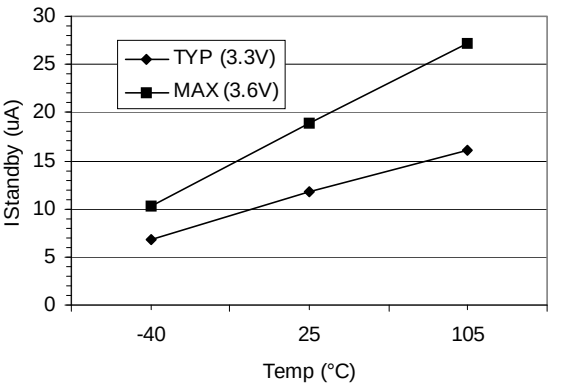
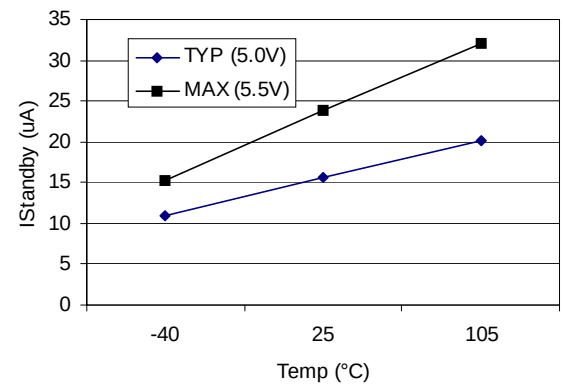


Figure 19. Power consumption in STANDBY mode (5 V range)



6.3.6 Memory characteristics

Flash memory

Subject to general operating conditions for V_{DD_IO} and V_{18}, T_A = -40 to 105 °C unless otherwise specified.

Table 26. Flash memory characteristics

Symbol	Parameter	Test Conditions	Value		Unit
			Typ	Max(1)	
t_{PW}	Word Program		35		µs
t_{PDW}	Double Word Program		60		µs
t_{PB0}	Bank 0 Program (256K)	Single Word programming of a checker-board pattern	2	4.9(2)	s
t_{PB1}	Bank 1 Program (16K)	Single Word programming of a checker-board pattern	125	224(2)	ms
t_{ES}	Sector Erase (64K)	Not preprogrammed (all 1) Preprogrammed (all 0)	1.54 1.176	2.94(2) 2.38(2)	s
t_{ES}	Sector Erase (8K)	Not preprogrammed (all 1) Preprogrammed (all 0)	392 343	560(2) 532(2)	ms
t_{ES}	Bank 0 Erase (256K)	Not preprogrammed (all 1) Preprogrammed (all 0)	8.0 6.6	13.7 11.2	s
t_{ES}	Bank 1 Erase (16K)	Not preprogrammed (all 1) Preprogrammed (all 0)	0.9 0.8	1.5 1.3	s
t_{RPD}	Recovery when disabled			20	µs
t_{PSL}	Program Suspend Latency			10	µs
t_{ESL}	Erase Suspend Latency			300	µs

1. Data based on characterisation not tested in production
2. 10K program/erase cycles.

Table 27. Flash memory endurance and data retention

Symbol	Parameter	Conditions	Value			Unit
			Min(1)	Typ	Max	
N_{END_B0}	Endurance (Bank 0 sectors)		10			kcycles
N_{END_B1}	Endurance (Bank 1 sectors)		100			kcycles
Y_{RET}	Data Retention	T_A=85° C	20			Years
t_{ESR}	Erase Suspend Rate	Min time from Erase Resume to next Erase Suspend	20			ms

1. Data based on characterisation not tested in production.

6.3.8 I/O port pin characteristics

General characteristics

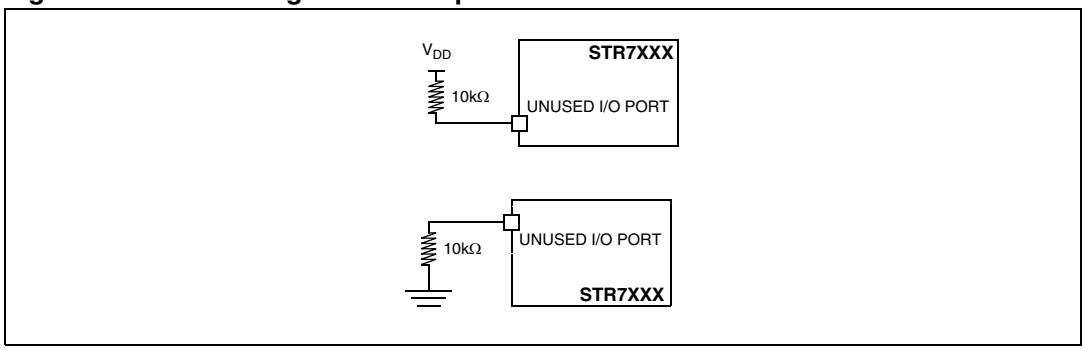
Subject to general operating conditions for V_{DD_IO} and T_A unless otherwise specified.

Table 32. General characteristics

I/O static characteristics							
Symbol	**Parameter**	**Conditions**		**Min**	**Typ**	**Max**	**Unit**
V_{IL}	Input low level voltage	TTL ports				0.8	V
V_{IH}	Input high level voltage			2			
V_{hys}	Schmitt trigger voltage hysteresis(1)				400		mV
$I_{INJ(PIN)}$	Injected Current on any I/O pin					± 4	mA
$\Sigma I_{INJ(PIN}$ (2)	Total injected current (sum of all I/O and control pins)					± 25	
I_{lkg}	Input leakage current on robust pins	See *Section 6.3.12 on page 72*					
	Input leakage current(3)	$V_{SS} \le V_{IN} \le V_{DD\_IO}$				±1	µA
I_S	Static current consumption(4)	Floating input mode			200		
R_{PU}	Weak pull-up equivalent resistor(5)	$V_{IN}=V_{SS}$	V_{DD_IO}=3.3 V	50	95	200	kΩ
			V_{DD_IO}=5 V	20	58	150	kΩ
R_{PD}	Weak pull-down equivalent resistor(5)	$V_{IN}=V_{DD\_IO}$	V_{DD_IO}=3.3 V	25	80	180	kΩ
			V_{DD_IO}=5 V	20	50	120	kΩ
C_{IO}	I/O pin capacitance				5		pF
$t_{w(IT)in}$	External interrupt/wake-up lines pulse time(6)			2			T_{APB}

1. Hysteresis voltage between Schmitt trigger switching levels.
2. When the current limitation is not possible, the V_{IN} absolute maximum rating must be respected, otherwise refer to $I_{INJ(PIN)}$ specification. A positive injection is induced by $V_{IN}>V_{DD\_IO}$ while a negative injection is induced by $V_{IN}<V_{SS}$. Refer to *Section 6.2 on page 32* for more details.
3. Leakage could be higher than max. if negative current is injected on adjacent pins.
4. Configuration not recommended, all unused pins must be kept at a fixed voltage: using the output mode of the I/O for example or an external pull-up or pull-down resistor (see *Figure 25*). Data based on design simulation and/or technology characteristics, not tested in production.
5. The R_{PU} pull-up and R_{PD} pull-down equivalent resistor are based on a resistive transistor.
6. To generate an external interrupt, a minimum pulse width has to be applied on an I/O port pin configured as an external interrupt source.

Figure 25. Connecting unused I/O pins



Output driving current

The GP I/Os have different drive capabilities:

- O2 outputs can sink or source up to +/-2 mA.
- O4 outputs can sink or source up to +/-4 mA.
- outputs can sink or source up to +/-8 mA or can sink +20 mA (with a relaxed V_{OL}).

In the application, the user must limit the number of I/O pins which can drive current to respect the absolute maximum rating specified in *Section 6.2.2* :

- The sum of the current sourced by all the I/Os on $V_{DD\_IO,}$ plus the maximum RUN consumption of the MCU sourced on $V_{DD\_IO,}$ can not exceed the absolute maximum rating IV_{DD_IO}.
- The sum of the current sunk by all the I/Os on V_{SS_IO} plus the maximum RUN consumption of the MCU sunk on V_{SS_IO} can not exceed the absolute maximum rating IV_{SS_IO}.

Subject to general operating conditions for V_{DD_IO} and T_A unless otherwise specified.

Output speed

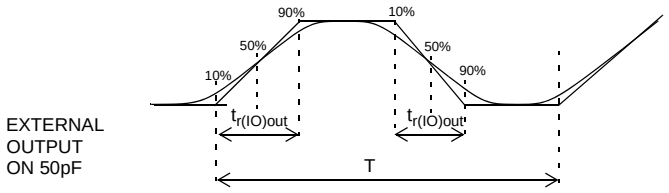
Subject to general operating conditions for V_{DD_IO} and T_A unless otherwise specified.

Table 34. Output speed

I/O dynamic characteristics for V_{DD_IO} = 3.0 to 3.6V and EN33 bit =1 or V_{DD_IO} = 4.5 to 5.5V and EN33 bit =0							
I/O Type	**Symbol**	**Parameter**	**Conditions**	**Min**	**Typ**	**Max**	**Unit**
O2	$f_{max(IO)out}$	Maximum Frequency(1)	C_L=50 pF			10	MHz
	$t_{f(IO)out}$	Output high to low level fall time(2)	C_L=50 pF Between 10% and 90%			30	ns
	$t_{r(IO)out}$	Output low to high level rise time(2)				33	
O4	$f_{max(IO)out}$	Maximum Frequency(1)	C_L=50 pF			25	MHz
	$t_{f(IO)out}$	Output high to low level fall time(2)	C_L=50 pF Between 10% and 90%			12	ns
	$t_{r(IO)out}$	Output low to high level rise time(2)				14	
O8	$f_{max(IO)out}$	Maximum Frequency(1)	C_L=50pF			40	MHz
	$t_{f(IO)out}$	Output high to low level fall time(2)	C_L=50 pF Between 10% and 90%			6	ns
	$t_{r(IO)out}$	Output low to high level rise time(2)				6	

1. The maximum frequency is defined as described in *Figure 26*.
2. Data based on product characterisation, not tested in production.

Figure 26. I/O output speed definition



Maximum frequency is achieved if (t_r + t_f) ≤ (2/3)T and if the duty cycle is (45-55%) when loaded by 50pF

Table 44. USB: Full speed electrical characteristics

Symbol	Parameter	Conditions	Min	Max	Unit
t_{rfm}	Rise/ Fall Time matching	t_r/t_f	90	110	%
V_{CRS}	Output signal Crossover Voltage		1.3	2.0	V

1. Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

6.3.12 10-bit ADC characteristics

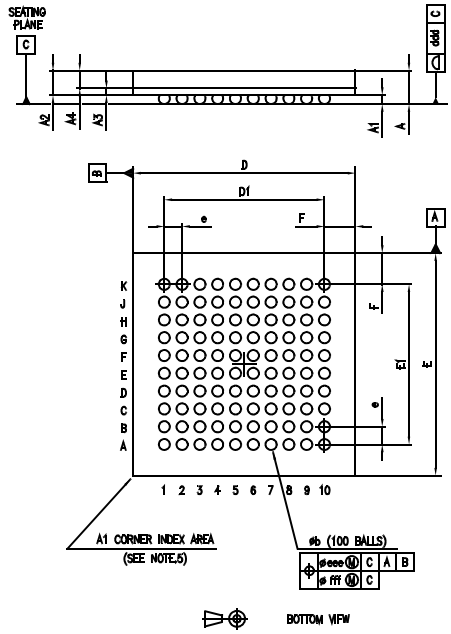
Subject to general operating conditions for V_{DDA_ADC}, f_{PCLK}, and T_A unless otherwise specified.

Table 45. 10-bit ADC characteristics

Symbol	Parameter	Conditions	Min	Typ(1)	Max	Unit
f_{ADC}	ADC clock frequency		0.4		8	MHz
V_{AIN}	Conversion voltage range(2)		V_{SSA_ADC}		V_{DDA_ADC}	V
R_{AIN}	External input impedance(3)(4)				10	kΩ
C_{AIN}	External capacitor on analog input(3)(4)				6.8	pF
I_{lkg}	Induced input leakage current	+400 µA injected on any pin			1	µA
		-400 µA injected on any pin except specific adjacent pins in *Table 46*			1	µA
		-400µA injected on specific adjacent pins in *Table 46*		40		µA
C_{ADC}	Internal sample and hold capacitor			3.5		pF
t_{CAL}	Calibration Time	f_{CK_ADC}=8 MHz	725.25			µs
			5802			$1/f_{ADC}$
t_{CONV}	Total Conversion time (including sampling time)	f_{CK_ADC}=8 MHz	3.75			µs
			30 (11 for sampling + 19 for Successive Approximation)			$1/f_{ADC}$
I_{ADC}		Sunk on V_{DDA_ADC}		3.7		mA

1. Unless otherwise specified, typical data are based on T_A=25°C. They are given only as design guidelines and are not tested.
2. Calibration is needed once after each power-up.
3. $C_{PARASITIC}$ represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (3 pF). A high $C_{PARASITIC}$ value will downgrade conversion accuracy. To remedy this, f_{ADC} should be reduced.
4. Depending on the input signal variation (f_{AIN}), C_{AIN} can be increased for stabilization time and reduced to allow the use of a larger serial resistor (R_{AIN}). It is valid for all f_{ADC} frequencies ≤ 8 MHz.

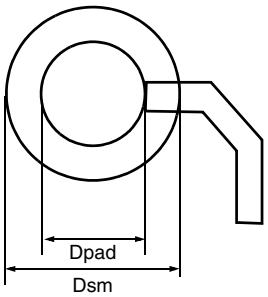
Figure 48. 100-ball low profile fine pitch ball grid array package



Dim.	mm			inches[1]		
	Min	Typ	Max	Min	Typ	Max
A			1.700			0.0669
A1	0.270			0.0106		
A2		1.085			0.0427	
A3		0.30			0.0118	
A4			0.80			0.0315
b	0.45	0.50	0.55	0.0177	0.0197	0.0217
D	9.85	10.00	10.15	0.3878	0.3937	0.3996
D1		7.20			0.2835	
E	9.85	10.00	10.15	0.3878	0.3937	0.3996
E1		7.20			0.2835	
e		0.80			0.0315	
F		1.40			0.055	
ddd			0.12			0.005
eee			0.15			0.006
fff			0.08			0.003
	Number of Balls					
N	100					

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 49. Recommended PCB design rules (0.80/0.75mm pitch BGA)



Dpad	0.37 mm
Dsm	0.52 mm typ. (depends on solder mask registration tolerance
Solder paste	0.37 mm aperture diameter
– Non solder mask defined pads are recommended – 4 to 6 mils screen print	

7.2.2 Selecting the product temperature range

When ordering the microcontroller, the temperature range is specified in the order code *Table 49: Order codes on page 81*.

The following example shows how to calculate the temperature range needed for a given application.

Assuming the following application conditions:

Maximum ambient temperature T_{Amax}= 82 °C (measured according to JESD51-2), I_{DDmax}=8 mA, V_{DD} = 5 V, maximum 20 I/Os used at the same time in output at low level with I_{OL} = 8 mA, V_{OL}= 0.4 V

$$P_{INTmax} = 8 \text{ mA} \times 5 \text{ V} = 400 \text{ mW}$$

$$P_{IOmax} = 20 \times 8 \text{ mA} \times 0.4\text{V} = 64 \text{ mW}$$

This gives: P_{INTmax}= 400 mW and P_{IOmax} 64 mW:

$$P_{Dmax} = 400 \text{ mW} + 64 \text{ mW}$$

Thus: P_{Dmax} = 464 mW

Using the values obtained in *Table 48* T_{Jmax} is calculated as follows:

– For LQFP100, 46°C/W

T_{Jmax} = 82° C + (46° C/W x 464 mW) = 82°C + 21°C = 103° C

This is within the range of the suffix 6 version parts (-40 < T_J < 105° C).

In this case, parts must be ordered at least with the temperature range suffix 6 (see *Table 49: Order codes on page 81*).

– For BGA64, 58°C/W

T_{Jmax} = 82° C + (58° C/W x 464 mW) = 82°C + 27°C = 109° C

This is within the range of the suffix 7 version parts (-40 < T_J < 125° C).

In this case, parts must be ordered at least with the temperature range suffix 7 (see *Table 49: Order codes on page 81*).

Figure 50. LQFP100 P_{Dmax} vs T_A

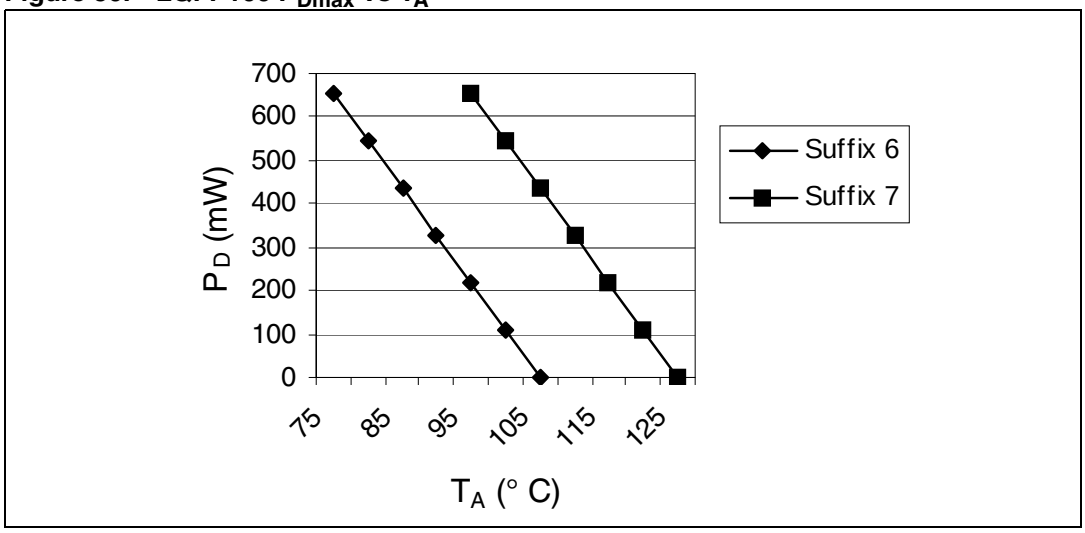


Table 49. Order codes (continued)

Order code	Flash Prog. Memory (Bank 0) Kbytes	Package	CAN Periph	USB Periph	Nominal Temp. Range (T_A)
STR755FV0T6	64	LQFP100 14x14	-	-	-40 to +85°C
STR755FV1T6	128				
STR755FV2T6	256				
STR755FV0H6	64	LFBGA100 10x10			
STR755FV1H6	128				
STR755FV2H6	256				

9 Revision history

Table 50. Document revision history

Date	Revision	Description of Changes
25-Sep-2006	1	Initial release
30-Oct-2006	2	Added power consumption data for 5V operation in *Section 6*
04-Jul-2007	3	Changed datasheet title from STR750F to STR750FXX STR751Fxx STR752Fxx STR755xx. Added *Table 1: Device summary on page 1* Added note 1 to *Table 6* Added STOP mode IDD max. values in *Table 14* Updated XT2 driving current in *Table 23.* Updated RPD in *Table 32* Updated *Table 21: XRTC1 external clock source on page 45* Updated *Table 34: Output speed on page 57* Added characteristics for *SSP synchronous serial peripheral in master mode (SPI or TI mode) on page 62* and *SSP synchronous serial peripheral in slave mode (SPI or TI mode) on page 65* Added characteristics for *SMI - serial memory interface on page 68* Added *Table 42: USB startup time on page 70*
23-Oct-2007	4	Updated *Section 6.2.3: Thermal characteristics on page 33* Updated P_D, T_J and T_A in *Section 6.3: Operating conditions on page 34* Updated *Table 20: XT1 external clock source on page 44* Updated *Table 21: XRTC1 external clock source on page 45* Updated *Section 7: Package characteristics on page 76* (inches rounded to 4 decimal digits instead of 3) Updated Ordering information *Section 8: Order codes on page 81*
17-Feb-2009	5	Modified note 3 below *Table 8: Current characteristics on page 33* Added AHB clock frequency for write access to Flash registers in *Table 10: General operating conditions on page 34* Modified note 3 below *Table 41: SDA and SCL characteristics on page 69*